28.3% Ultra Triple Junction (UTJ)



2 Per (26.6 cm²)



LEONE (59.6 cm²)

High Efficiency Space Photovoltaics

Product Features

- Small and large cell sizes offered for optimum packing factor and cost competitiveness
- All sizes qualified for LEO and GEO missions
- Discrete Si bypass diode protection
- Performance for cells <32 cm² is 28.4% efficiency (minimum average @ max power, 28°C, AM0)
- Performance for cells >32 cm² is 27.9% efficiency (minimum average @ max power, 28°C, AM0)
- Available as CIC assembly (Cell-Interconnect-Coverglass with diode) for ease of integration or delivered on completed solar panels (please refer to Panel Data Sheet)

Space Heritage

- Sustained quality without a single anomaly throughout six decades of space flight heritage
- Highest competitive EOL dollar per Watt solutions
- More than 4 million multi-junction cells delivered
- More than 2 MW of multi-junction arrays on orbit
- Large area LEONE cell (59.6 cm²) delivered on solar panels for over 37 satellites (LEO constellation)
- 1 MW annual capacity cells and panels
- On orbit performance for multi-junction solar cells validated to +1% of ground test results on average

Qualification

Key Qualification Results			
Low Earth Orbit (LEO)	> 75,000 cycles		
Geostationary Orbit (GEO)	> 15,550 cycles		
Interplanetary Missions	Mars, Jupiter, Asteroid		
Testing	ESD Survivability Tested to ISO Standards		
Qualification	Fully Qualified for all Mission Types		

Product Description

Substrate	Germanium	
Solar Cell Structure	GaInP ₂ /InGaAs/Ge	
Method	Metal Organic Vapor Phase Epitaxy	
Device Design	Monolithic, two terminal triple junction. n/p GaInP ₂ , InGaAs, and Ge solar cells interconnected with two tunnel junctions	
Standard Sizes	26.6 cm ² and 59.6 cm ² are most cost effective and common standard sizes; other sizes available	
Assembly Method	Welded	
CIC Assembly	Coverglass thickness range from 3 mils to 30 mils with various coatings. Interconnects available with either out-of-plane or in-plane stress relief	

Ultra Triple Junction (UTJ)

Typical Electrical Parameters

(AM0 (135.3 mW/cm²) 28°C, Bare Cell)

	> 50 cm ²
17.14 mA/cm ²	17.22 mA/cm ²
16.38 mA/cm ²	16.46 mA/cm ²
16.48 mA/cm ²	16.56 mA/cm ²
2.660 V	2.660 V
2.350 V	2.300 V
2.310 V	2.270 V
0.85	0.83
28.1%	27.8%
28.4%	27.9%
	16.38 mA/cm² 16.48 mA/cm² 2.660 V 2.350 V 2.310 V 0.85 28.1%

Radiation Degradation

(Fluence 1MeV Electrons/cm²)

Parameters	1x10 ¹⁴	5x10 ¹⁴	1x10 ¹⁵
Imp/Imp ₀	0.99	0.98	0.96
Vmp/Vmp ₀	0.94	0.91	0.89
Pmp/Pmp ₀	0.93	0.89	0.86

Thermal Properties

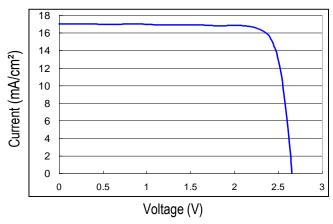
Solar Absorptance	0.92 (5 mil CMG-AR, 0.90 for bare cells)
Emittance (Normal)	0.85 (Ceria Doped Microsheet)

Temperature Coefficients (15°C - 80°C) (Fluence 1MeV Electrons/cm²)

Parameters	BOL	5x10 ¹⁴	1x10 ¹⁵
Jmp (µA/cm²/°C)	1.2	5.3	6.9
Jsc (μA/cm²/°C)	5.3	6.5	6.9
Vmp (mV/°C)	-6.5	-6.7	-6.8
Voc (mV/°C)	-5.9	-6.3	-6.5

Typical IV Characteristic

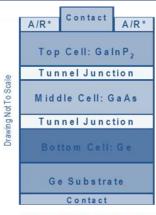
AM0 (135.3 mW/cm²) 28°C, Bare Cell



Weight

84 mg/ cm² (Bare) @ 140 µm (5.5 mil) Ge wafer thickness

Solar Cell Structure



*A/R: Anti-Reflective Coating

Intellectual Property

This product is protected by Spectrolab's portfolio of patents including the following:

- **6**,150,603
- **6**,255,580
- **7**,119,271
- **6**,380,601
- **7**,126,052

Regulatory

Spectrolab's products are fully qualified and are ISO9001 and AS9100 certified